

V.G.Zubkov, S.A.Turzhevsky, V.A.Pereliaev, A.I.Liechtenstein,

V.A.Gubanov

Institute of Chemistry, Ural Branch,  
Academy of Sciences, Sverdlovsk, USSR.

The information available on the BaO(SrO)-NbO-NbO<sub>2</sub> system with the niobium atom in the lower oxidation degree is very limited. Very few compounds have been found previously in this system. They are BaNbO<sub>3</sub>, Sr<sub>x</sub>NbO<sub>3</sub> (0,7 ≤ x ≤ 1), Ba<sub>2</sub>Nb<sub>2</sub>O<sub>9</sub>, SrNb<sub>8</sub>O<sub>14</sub> and some suggestions on the BaNb<sub>8</sub>O<sub>14</sub> existence have been made also. At the same time Nb-based oxide compounds could be quite interesting in the search of new noncopper high T<sub>c</sub> superconductors (see, for example, [1,2]).

In the present paper we have studied Ba(Sr)-Nb<sub>x</sub>O<sub>2x-2</sub> (I) and Ba<sub>2</sub>(Sr<sub>2</sub>)-Nb<sub>x</sub>O<sub>2x-1</sub> (II) compositions in the phase diagram of BaO(SrO)-NbO-NbO<sub>2</sub> system. The synthesis of the materials has been carried out in vacuum at the temperatures of 1000-1500 C. Barium carbonate and niobium pentoxide have been used as initial components. X-ray analysis has been carried out at DRON-UM1 CuK<sub>α</sub> radiation.

In the subsystem (I) the following individual compounds have been obtained: BaNb<sub>4</sub>O<sub>6</sub> (x=4), BaNb<sub>5</sub>O<sub>8</sub> and SrNb<sub>5</sub>O<sub>8</sub> (x=5), BaNb<sub>8</sub>O<sub>14</sub> and SrNb<sub>8</sub>O<sub>14</sub> (x=8). In the subsystem (II) Ba<sub>2</sub>Nb<sub>5</sub>O<sub>9</sub> and Sr<sub>2</sub>Nb<sub>5</sub>O<sub>9</sub> (x=5) have been separated only. The crystal structure of the compounds obtained has been studied by the neutron diffraction experiments with the use of Rietveld analysis. The crystal lattice of BaNb<sub>4</sub>O<sub>6</sub>, Ba<sub>2</sub>Nb<sub>5</sub>O<sub>9</sub> and Sr<sub>2</sub>Nb<sub>5</sub>O<sub>9</sub> appears to have P4mmm, z=1 space group and they represent the series of n · (BaNbO<sub>3</sub>) · 3(NbO) compounds with a<sub>r</sub> ≈ a(NbO), c<sub>r</sub> ≈ (n+1) · a(BaNbO<sub>3</sub>), where n is the thickness of perovskite layer. All of the compounds obtained have typical perovskite layered structure with two-dimensional perovskite layers and niobium monoxide layers perpendicular to c axis. BaNb<sub>5</sub>O<sub>8</sub> contains one-dimensional cluster of niobium monoxide, which is parallel to c axis. This compound possesses the P4/m, z=1 space group lattice. Crystal lattice parameters are closely related with niobium monoxide block size: a<sub>r</sub> = 6,608 Å ≈ √(5/2) a(NbO), c<sub>r</sub> = 4,107 Å ≈ a(NbO). BaNb<sub>8</sub>O<sub>14</sub> and SrNb<sub>8</sub>O<sub>14</sub> are isostructural (of Pbam, z=2 space group) and contain chains of isolated niobium monoxide clus-

ters.

The study of electrophysical properties carried out reveals the compounds with one-dimensional niobium monoxide clusters -  $\text{BaNb}_5\text{O}_8$  and two-dimensional clusters -  $\text{BaNb}_4\text{O}_6$ ,  $\text{Ba}_2\text{Nb}_5\text{O}_9$ ,  $\text{Sr}_2\text{Nb}_5\text{O}_9$  are paramagnetics of the Curie-Weiss type and reveal the metallic character of  $\rho(T)$  dependence ( $\rho_{293} \approx 10^{-4}$  ohm-cm). At the same time the compounds with isolated clusters -  $\text{BaNb}_8\text{O}_{14}$  and  $\text{SrNb}_8\text{O}_{14}$  are weak diamagnetics at the room temperature and have metal-semiconductor phase transition at  $T_t \approx 270\text{K}$ . Isomorphic substitution of Ba(Sr) for La results in the shift of phase transition to the low temperature region (1% of La -  $T_t \approx 80\text{K}$ , 2% of La -  $T_t \approx 10\text{K}$ ).

The next peculiarity of  $\text{BaNb}_8\text{O}_{14}$  and  $\text{SrNb}_8\text{O}_{14}$  compounds is their tendency to oxygen absorption, their mass is increased by 1% under the yeast treatment ( $T=250^\circ\text{C}$ ) in the air.

The results obtained show that all the Sr and Ba niobium oxides with the niobium in the lower oxidation states form the lattices containing niobium monoxide clusters which could be isolated, one- or two-dimensional. Compound with isolated clusters satisfy the superconductivity criterion by Sleight [3]. The metal-semiconductor phase transition appear to realize at electron concentration in the clusters equal to 14 instead of 22 as in Chevrel phases.

In order to estimate of some of the compounds obtained possess similar peculiarities in electronic structure as copper high- $T_c$  superconductors, we carried out the LMTO band structure calculations for the following niobium compounds:  $\text{SrNbO}_3$ ,  $\text{La}_{0.66}\text{Nb}_2\text{O}_6$ ,

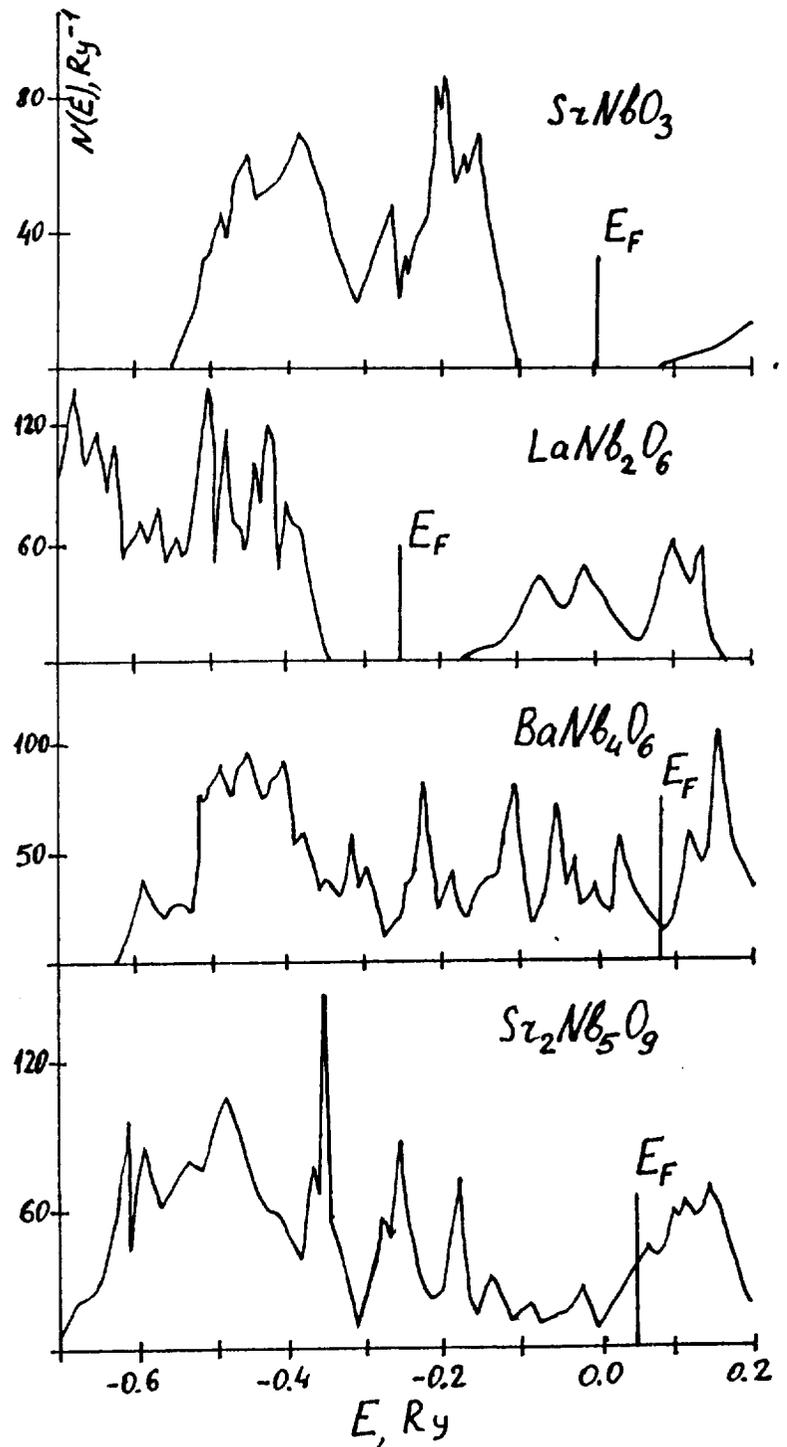


Fig.1. The total density of states

ORIGINAL PAGE IS  
OF POOR QUALITY

$\text{BaNb}_4\text{O}_6$ ,  $\text{Sr}_2\text{Nb}_5\text{O}_9$ . The calculations performed showed that for the  $\text{SrNbO}_3$  and  $\text{La}_{0.66}\text{Nb}_2\text{O}_6$  compounds Nb4d and O2p bands are complete-

ly separated and the Fermi level is situated between them.

In the  $\text{BaNb}_4\text{O}_6$  and  $\text{Sr}_2\text{Nb}_5\text{O}_9$  partial hybridization of Nb4d and O2p states at the energies lower than  $E_F$  takes place and the common Nb4d-O2p band is formed (Fig.1). For  $\text{BaNb}_4\text{O}_6$  O2p contributions at the Fermi energy (which are typical for high- $T_c$  copper superconductors) are missing, but for  $\text{Sr}_2\text{Nb}_5\text{O}_9$  quite essential oxygen atoms contributions at the  $E_F$  appear. Their value could be significantly increased when the Fermi level is shifted, for example, when doping the crystal lattice by atoms of another valence or changing the oxygen stoichiometry ratio. In some cases, probably, the characteristic picture of high- $T_c$  superconductor electronic structure could appear together, hopefully, with superconductivity properties.

#### REFERENCES

1. T.Ogushi, Y.Hakuraku, Y.Honjo, G.N.Suresha, S.Higo, Y.Ozono, I.Kawano and T.Numata, J.of Low Temp.Phys. 70(1988)485
2. T.Ogushi, S.Higo, N.G.Suresha, Y.Honio, Y.Ozono, I.Kawano and Y.Hakuraku, J.of Low Temp.Phys.73(1988)305
3. A.W.Sleight, Chemtronics, 2(1987)116